

## Supporting Information

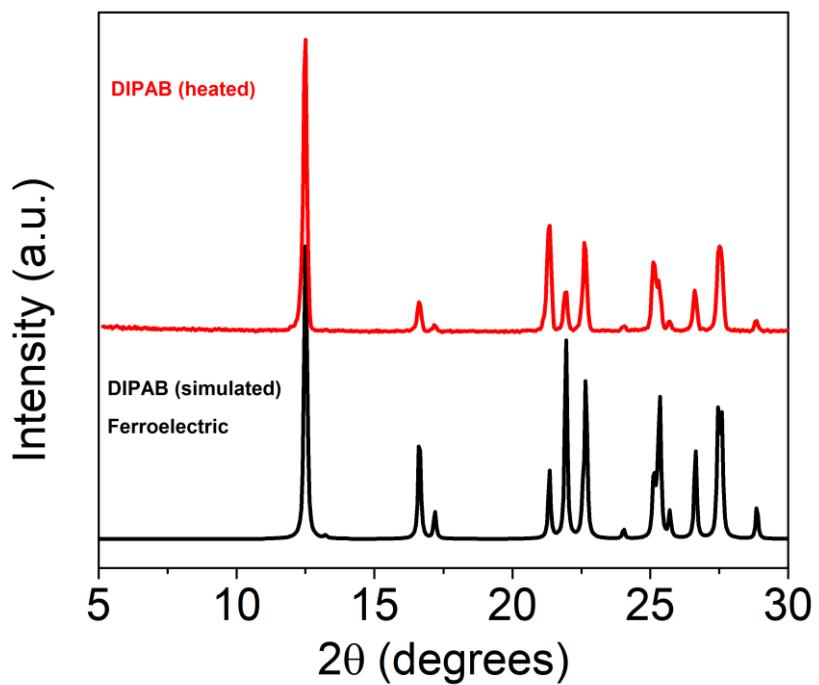
### **Triboelectric nanogenerator based on electrospun molecular ferroelectric composite nanofibers for energy harvesting**

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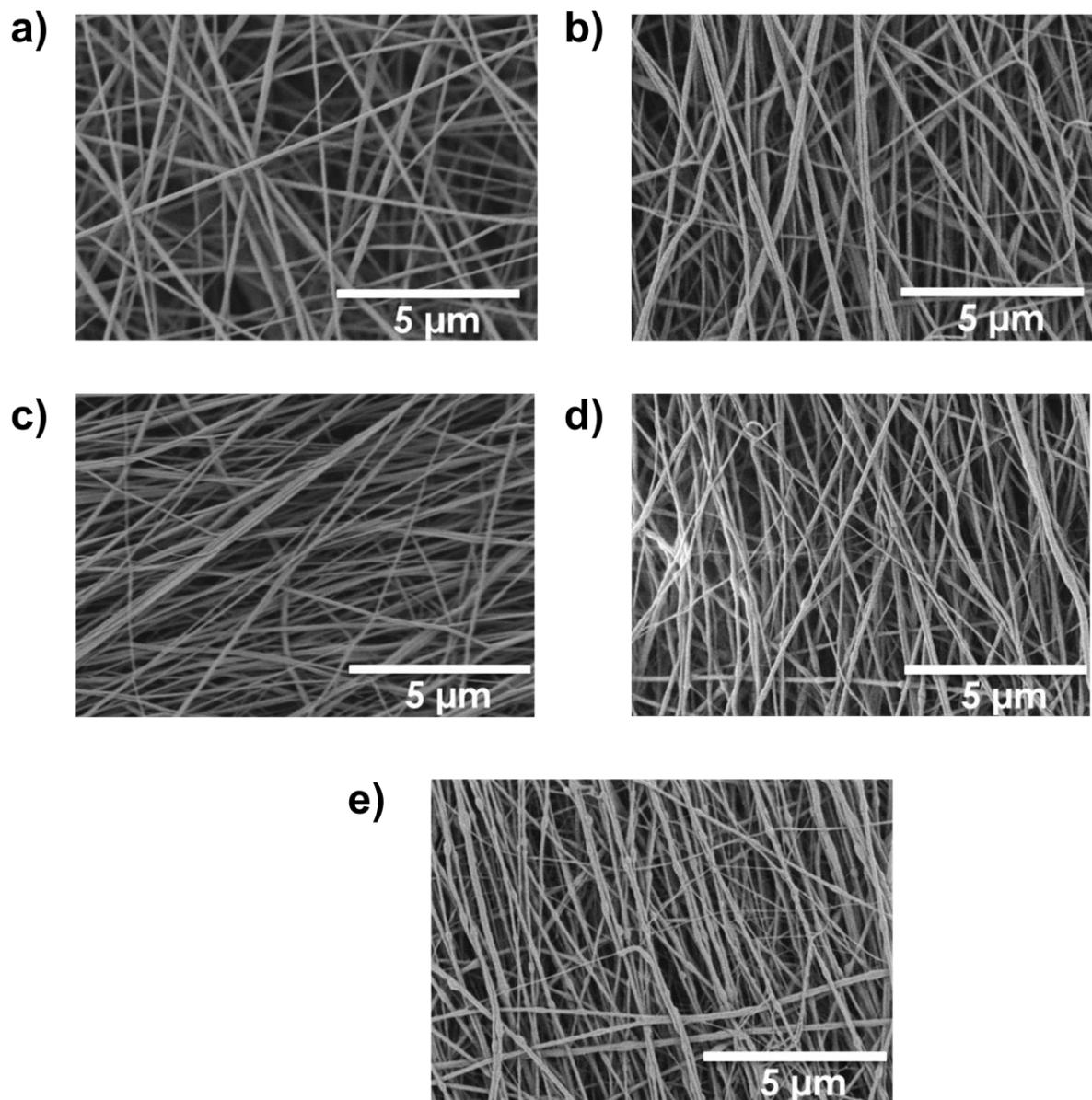
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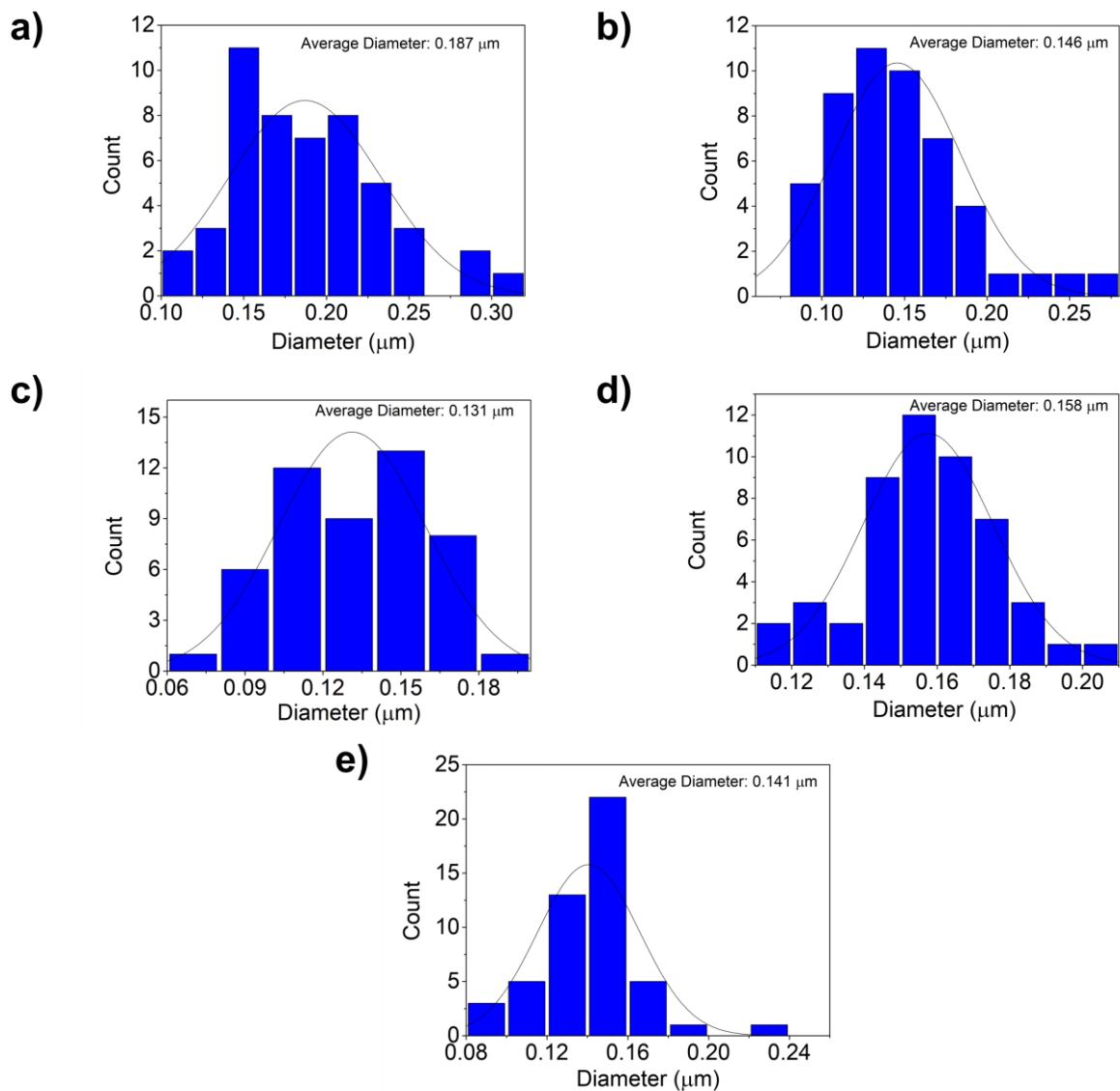
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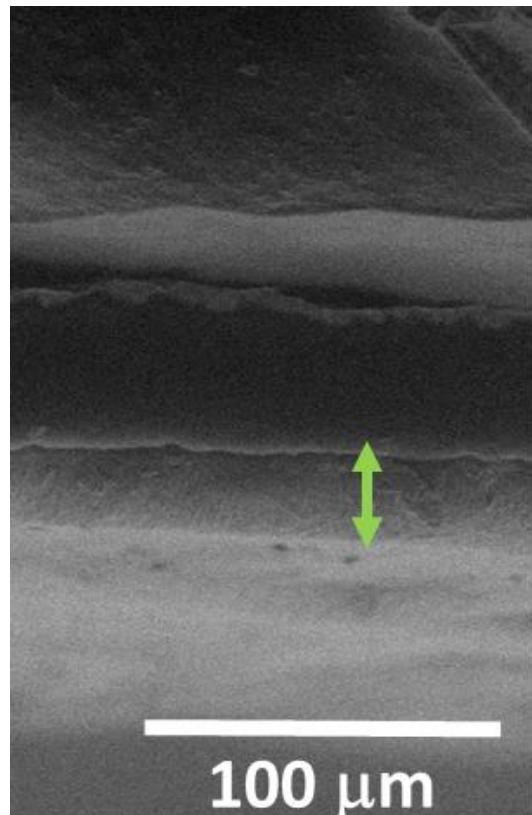
**Fig. S1.** The PXRD pattern of DIPAB after heat treatment.



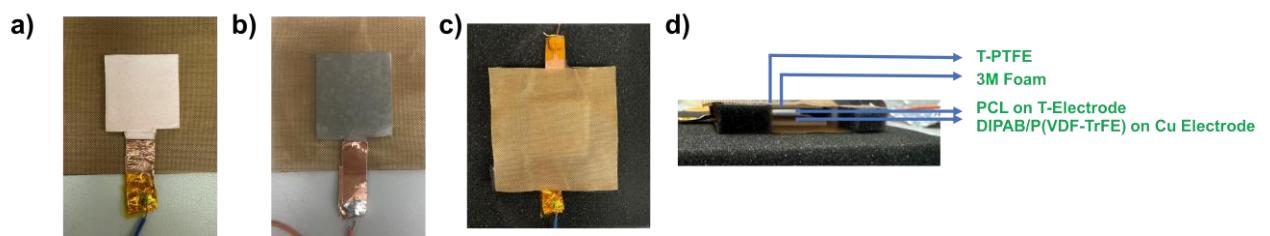
**Fig. S2.** SEM images of (a) P(VDF-TrFE), (b) 3 wt% (c) 5 wt% (d) 10 wt% and (e) 15 wt% DIPAB/P(VDF-TrFE) fibers.



**Fig. S3.** Fiber diameter distributions of (a) P(VDF-TrFE), (b) 3 wt% (c) 5 wt% (d) 10 wt% and (e) 15 wt% DIPAB/P(VDF-TrFE) electrospun mats.



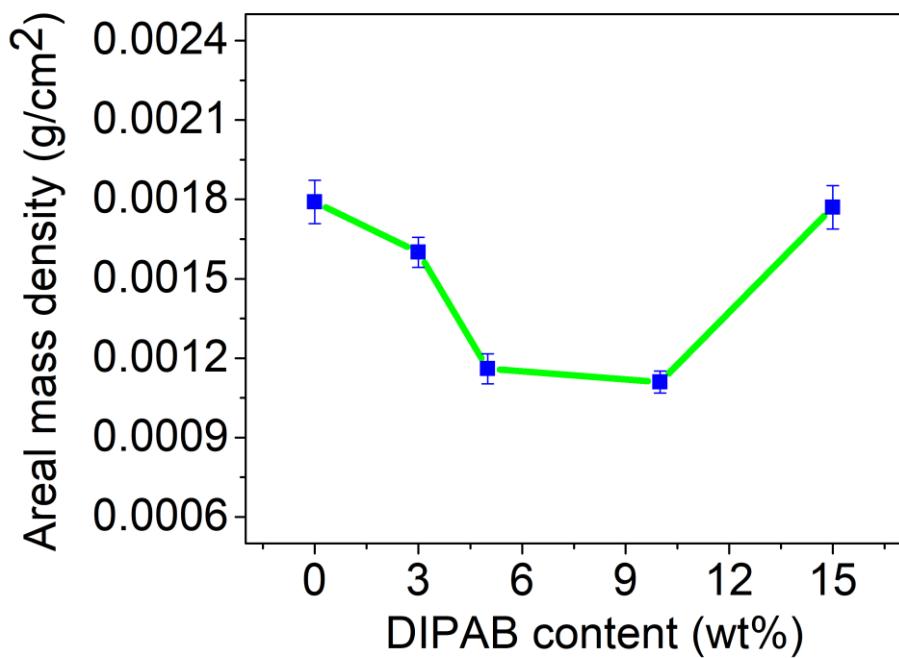
**Fig. S4.** Cross-section SEM image of 5 wt% DIPAB/P(VDF-TrFE) fiber mat showcasing formation of 23  $\mu\text{m}$  thick film.



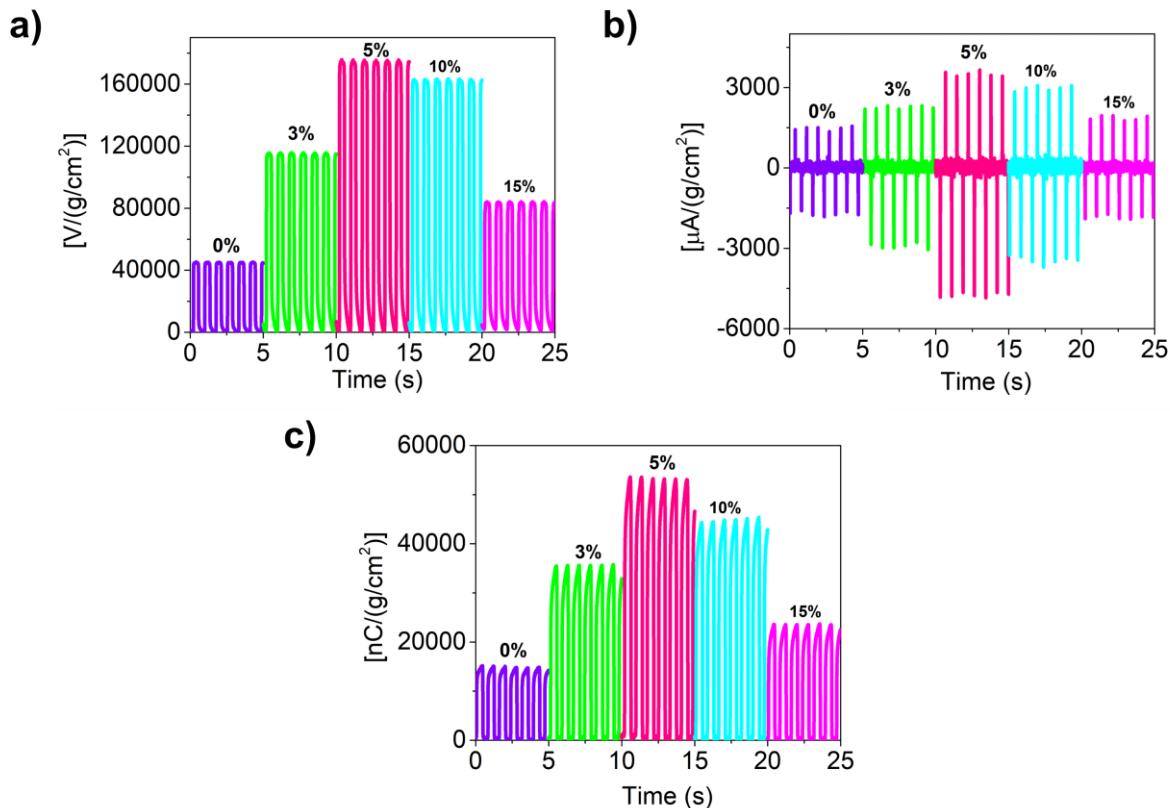
**Fig. S5.** Construction of DIPAB/P(VDF-TrFE) fiber mat device using (a) varied wt% DIPAB/P(VDF-TrFE) fiber mat as negative layers and (b) PCL film as a positive layer. (c),(d) Photograph of the fabricated device.

**Table S1.** Table comparing our TENG device with reported ferroelectric devices.

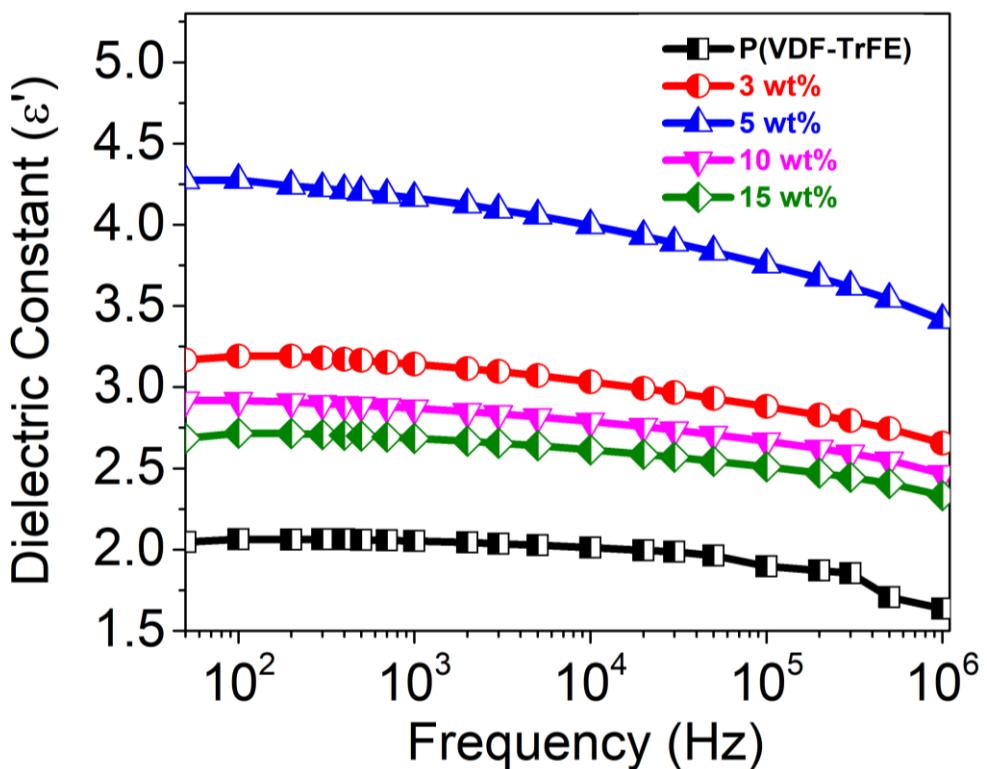
Active Layers	Voltage (V)	Power density (mW/m <sup>2</sup> )	References
BaTiO <sub>3</sub> /PDMS and Nylon cloth	72.2	55	[1]
BaTiO <sub>3</sub> /PVA and PDMS	72	70 µW	[2]
Bi <sub>2</sub> WO <sub>6</sub> /PVDF-TrFE and Cu	205	-	[3]
ZnAl-LDH/ PVDF	230.6	4300	[4]
ZnO/PVDF and PTFE	80	245	[5]
BCZTBH/PDMS and Al	300	157	[6]
CA/PEI(b) and Gelatin/ImClO <sub>4</sub> /Ti <sub>3</sub> C <sub>2</sub>	300	5000	[7]
CS/-γ-gly and PTFE	79	790	[8]
SF/15% γ-gly and PTFE	80	228	[9]
<b>DIPAB/P(VDF-TrFE) and PCL</b>	<b>203.8</b>	<b>416.2</b>	<b>This work</b>



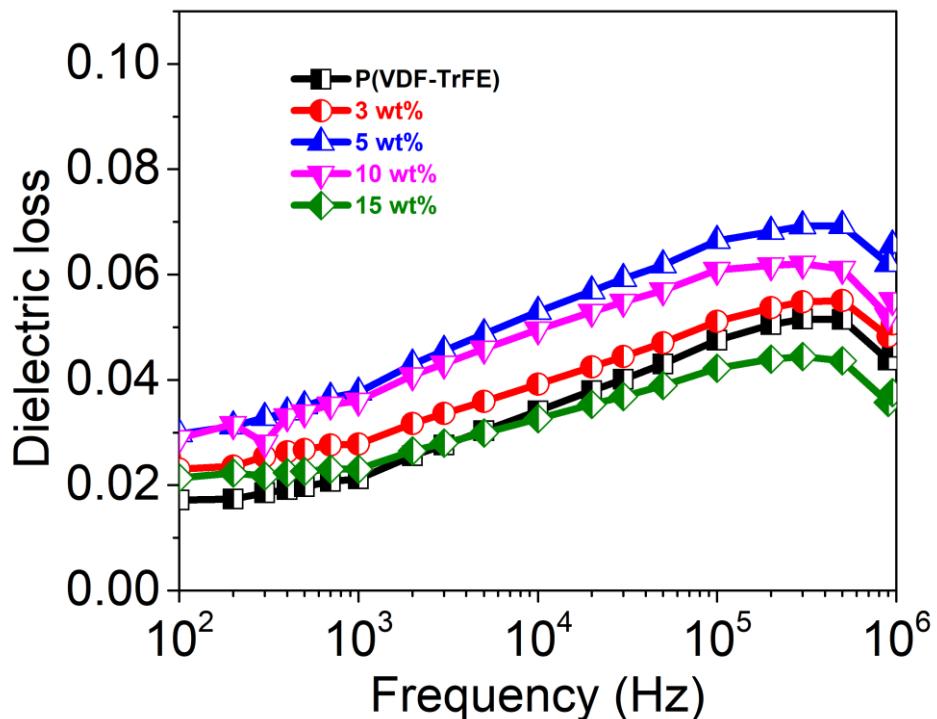
**Fig. S6.** Areal mass density of all wt% DIPAB/P(VDF-TrFE) fiber mats.



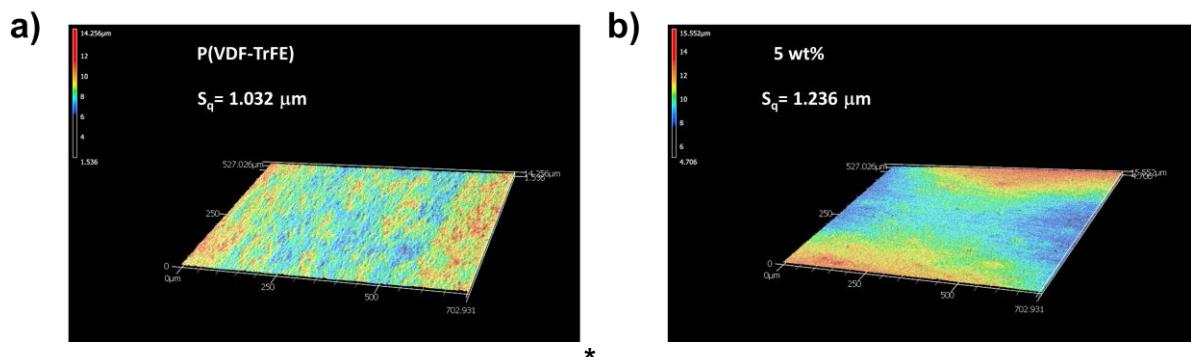
**Fig. S7.** Comparative (a) output voltage, (b) current performance and (c) charge profile of all wt% DIPAB/P(VDF-TrFE) fiber-based devices normalized by areal mass density.



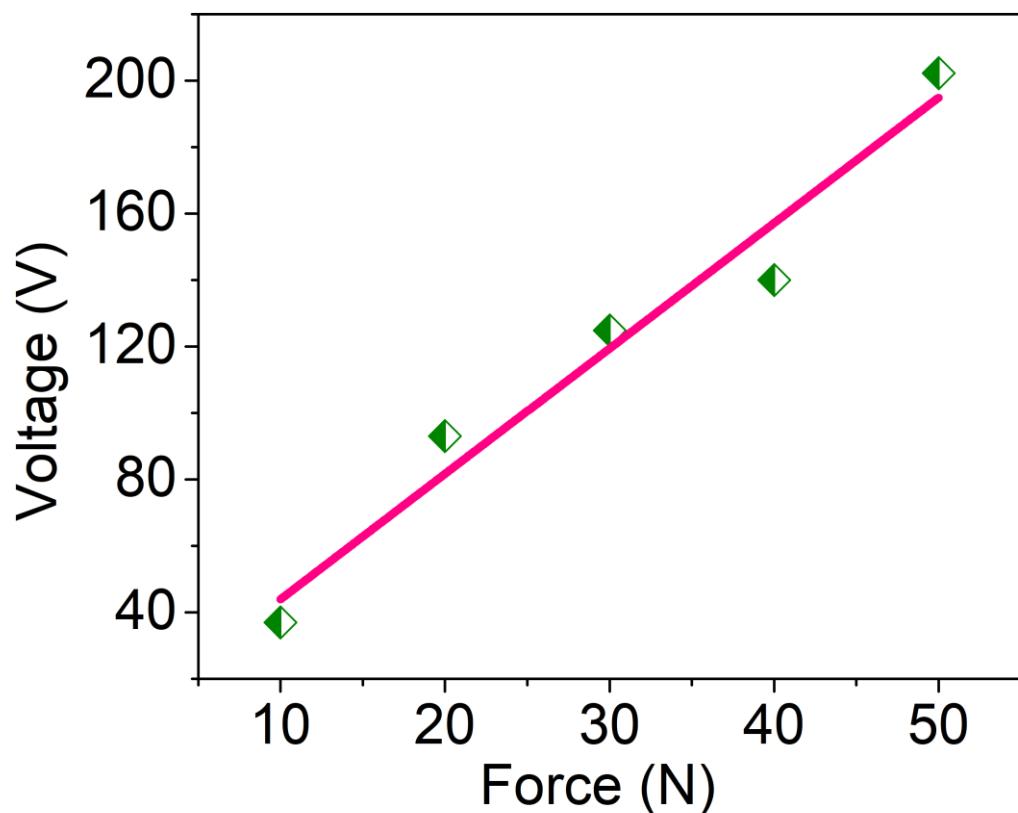
**Fig. S8.** Frequency-dependent dielectric constant ( $\epsilon'$ ) of DIPAB/P(VDF-TrFE) fiber mats at room temperature.



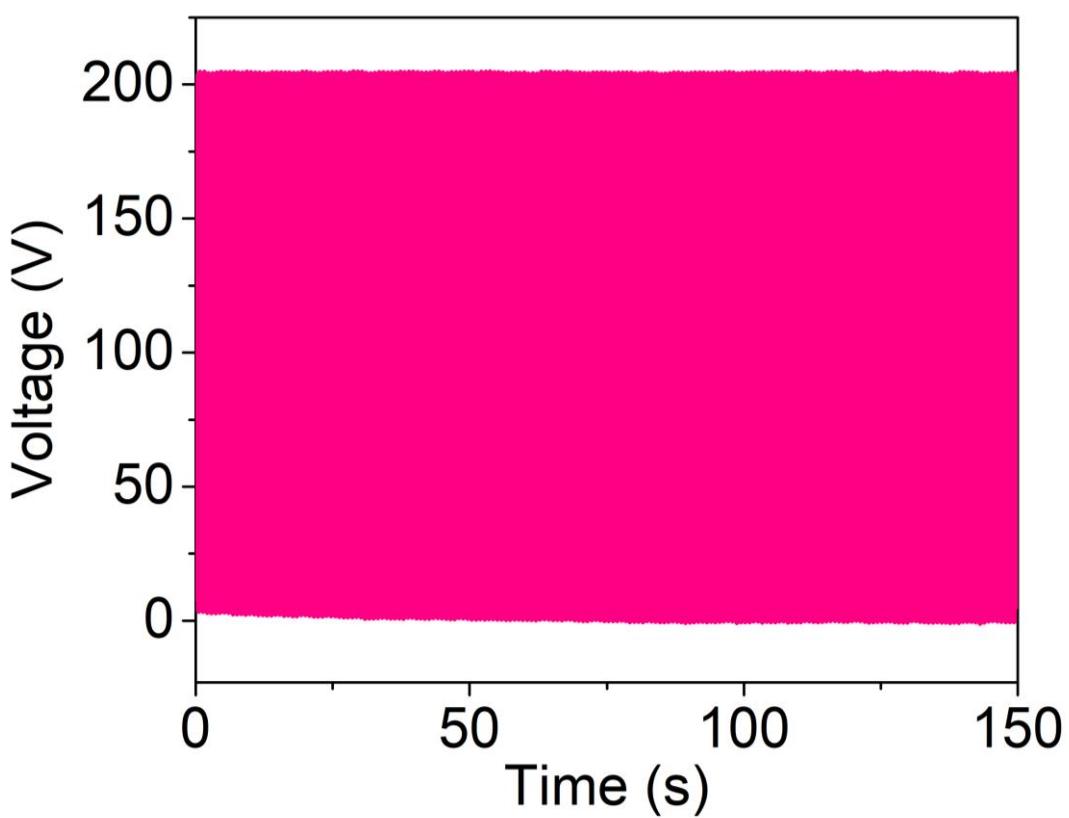
**Fig. S9.** Frequency-dependent dielectric loss plot of DIPAB/P(VDF-TrFE) fiber mats at room temperature.



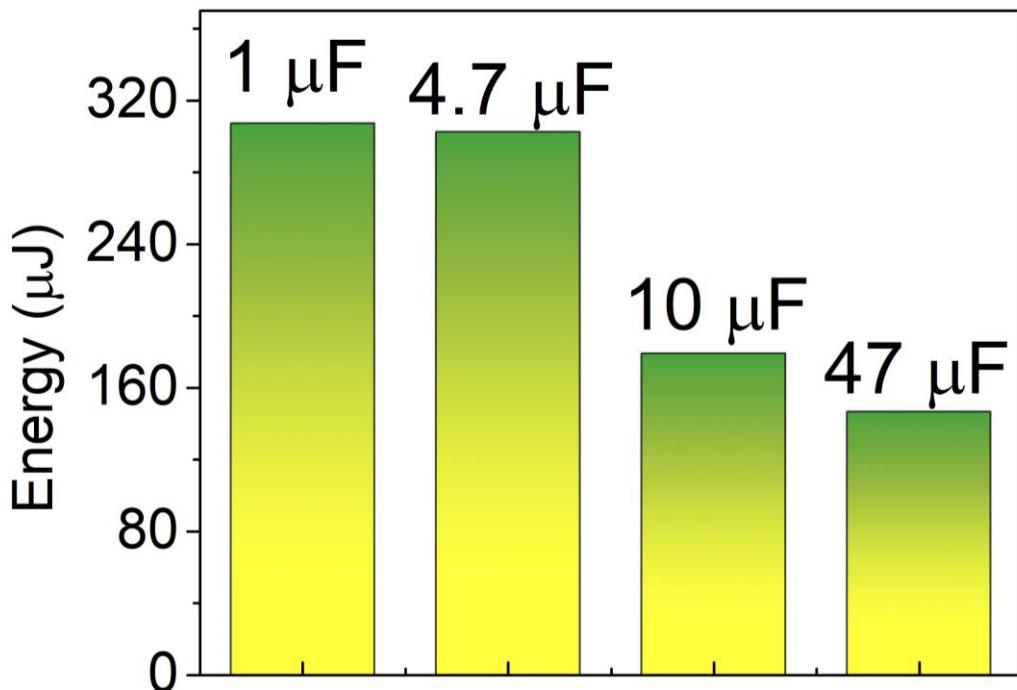
**Fig. S10.** 3D images of a) P(VDF-TrFE) and (b) 5 wt% DIPAB/P(VDF-TrFE) fiber mats.



**Fig. S11.** Linear plot for the variation in voltage with the applied force on 5 wt% DIPAB/P(VDF-TrFE) fiber-based device.



**Fig. S12.** Mechanical durability test performed on 5 wt% DIPAB/P(VDF-TrFE) fiber-based device.



**Fig. S13.** Electrical energy stored across (a) 1, (b) 4.7, (c) 10 and (d) 47  $\mu\text{F}$  capacitors employing the 5 wt% DIPAB/P(VDF-TrFE) fiber based device.

**References:**

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